NPN Triple Diffused Planar Silicon Transistor



2SC3991

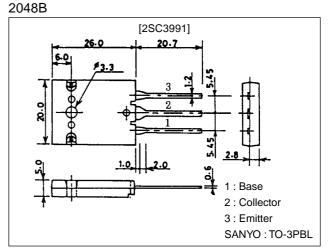
# 500V/50A Switching Regulator Applications

### Features

- $\cdot$  High breakdown voltage, high reliability.
- $\cdot$  Fast switching speed (t\_f=0.1 \mbox{\mu s typ}).
- $\cdot$  Wide ASO.
- · Adoption of MBIT process.

## **Package Dimensions**

unit:mm



# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		800	V
Collector-to-Emitter Voltage	VCEO		500	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	۱ <sub>C</sub>		50	Α
Collector Current (Pulse)	ICP	PW≤300µs, duty cycle≤10%	70	Α
Base Current	Ι <sub>Β</sub>		14	Α
Collector Dissipation	PC		3.5	W
		Tc=25°C	300	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### **Electrical Characteristics at Ta = 25°C**

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =500V, I <sub>E</sub> =0			10	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =5V, I <sub>C</sub> =0			10	μΑ
DC Current Gain	h <sub>FE</sub> 1*	$V_{CE}=5V, I_{C}=4.8A$	15		50	
	h <sub>FE</sub> 2	$V_{CE}=5V, I_{C}=24A$	8			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =10V, I <sub>C</sub> =4.8A		18		MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		560		pF

\*: The  $h_{FE1}$  of the 2SC3991 is classified as follows. When specifying the  $h_{FE1}$  rank, specify two ranks or more in principle.

15 L 30 20 M 40 30 N 50

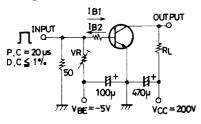
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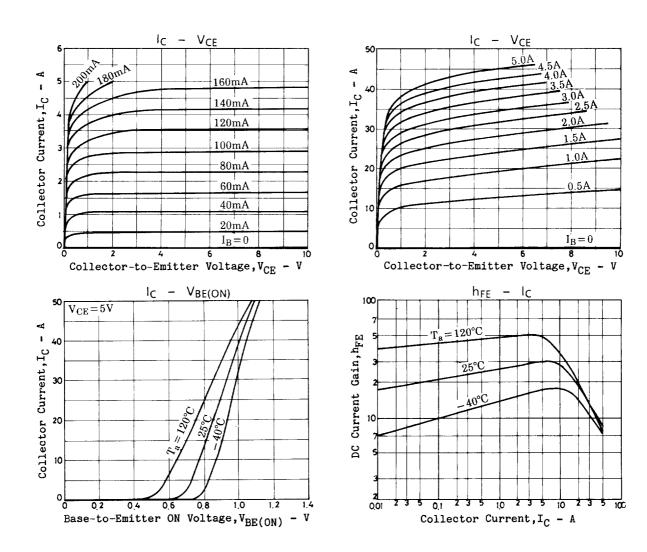
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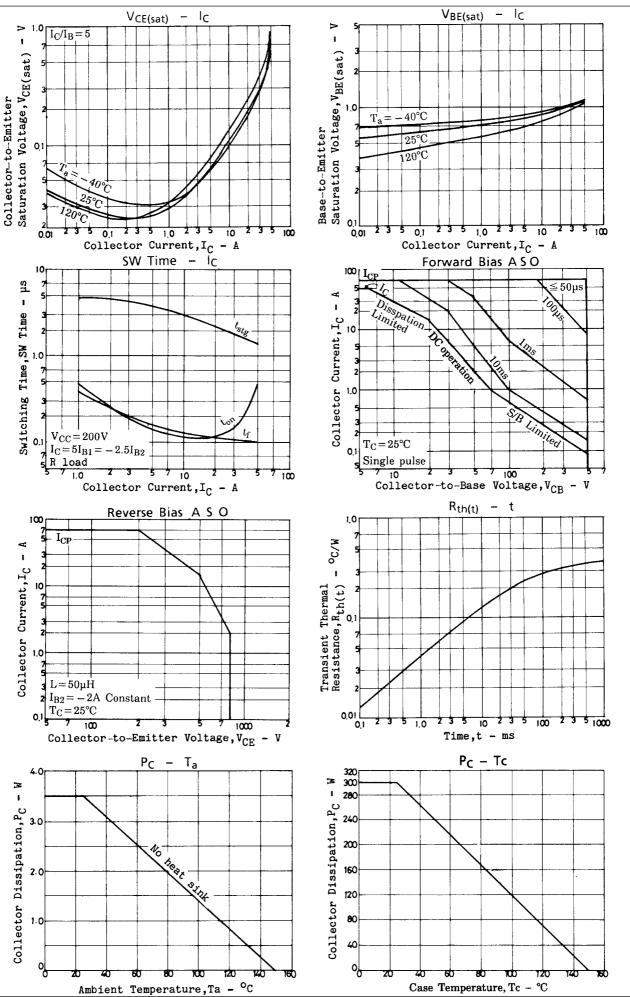
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =24A, I <sub>B</sub> =4.8A			1.0	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =24A, I <sub>B</sub> =4.8A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =1mA, I <sub>E</sub> =0	800			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =10mA, R <sub>BE</sub> =∞	500			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =1mA, I <sub>C</sub> =0	7			V
Collector-to-Emitter Sustain Voltage	V <sub>CEX(sus)</sub>	I <sub>C</sub> =15A, I <sub>B1</sub> =-I <sub>B2</sub> =-2A, L=100µH, clamped	500			V
Turn-ON Time	ton	$V_{CC}=200V, 5I_{B1}=-2.5I_{B2}=I_{C}=26A, R_{L}=7.7\Omega$			0.5	μs
Storage Time	<sup>t</sup> stg	$V_{CC}$ =200V, 5I <sub>B1</sub> =-2.5I <sub>B2</sub> =I <sub>C</sub> =26A, R <sub>L</sub> =7.7 $\Omega$			3.0	μs
Fall Time	t <sub>f</sub>	$V_{CC}$ =200V, 5I <sub>B1</sub> =-2.5I <sub>B2</sub> =I <sub>C</sub> =26A, R <sub>L</sub> =7.7 $\Omega$			0.3	μs

### Switching Time Test Circuit



Unit (resistance :  $\Omega$ , capacitance : F)





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